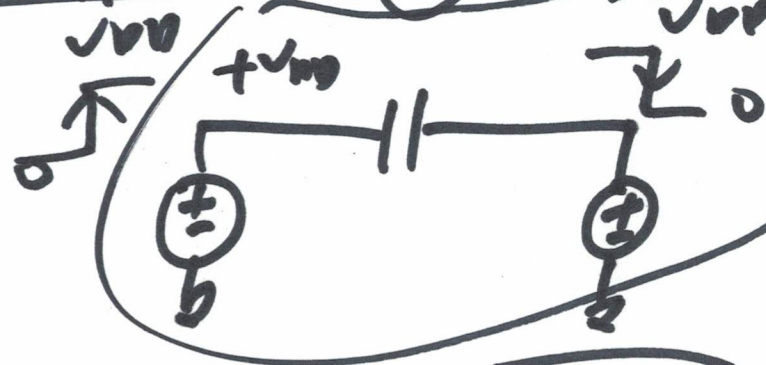
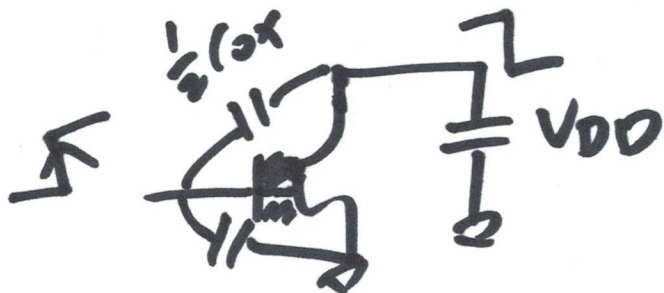


Miller Effect

(1)

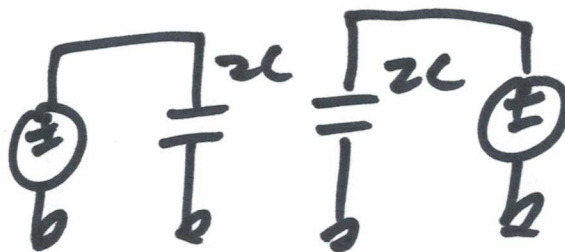


$$Q = VC$$

$$\Delta V = 2V_{DD}$$

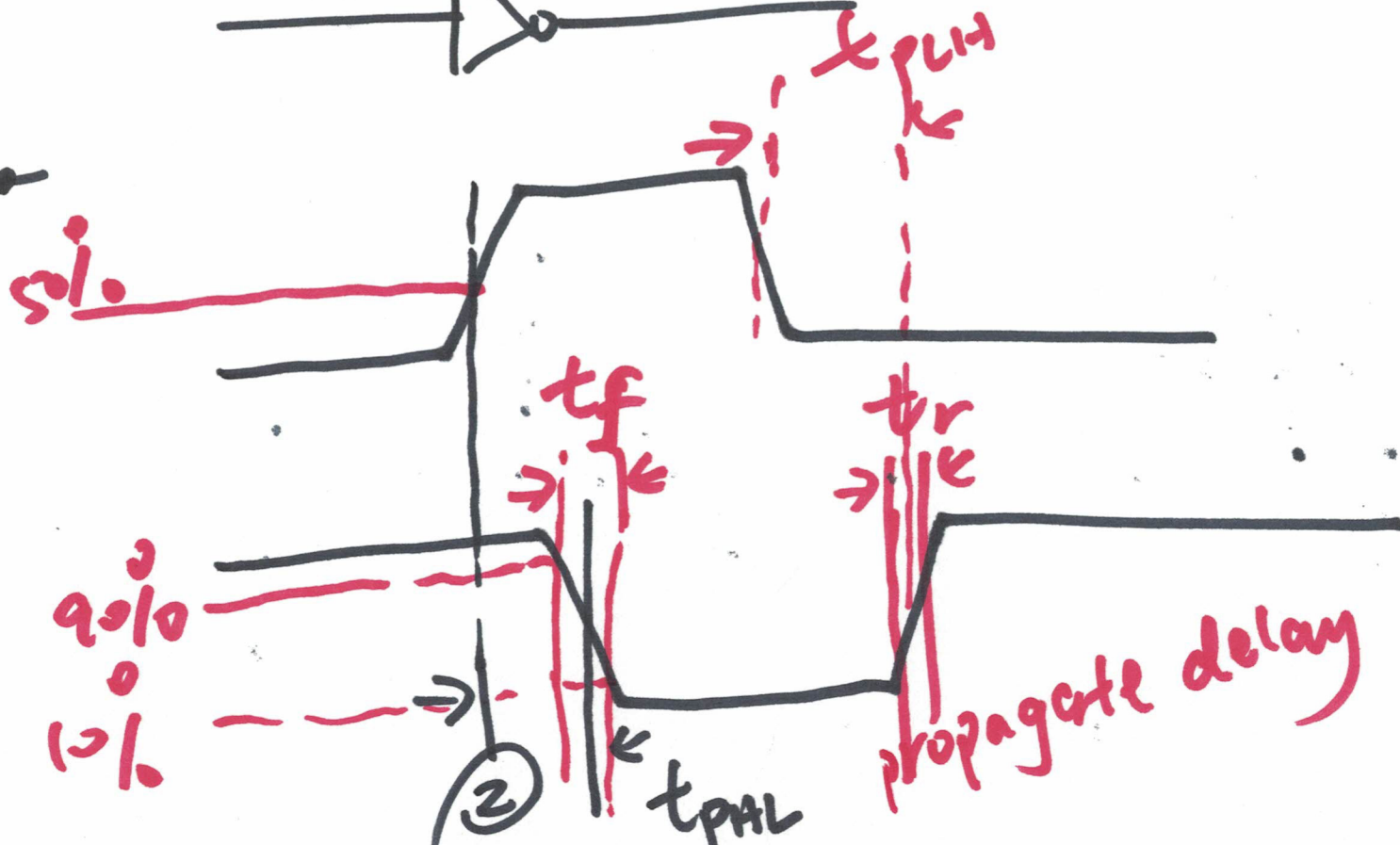
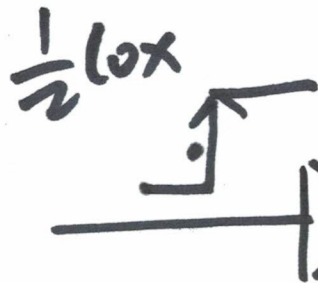
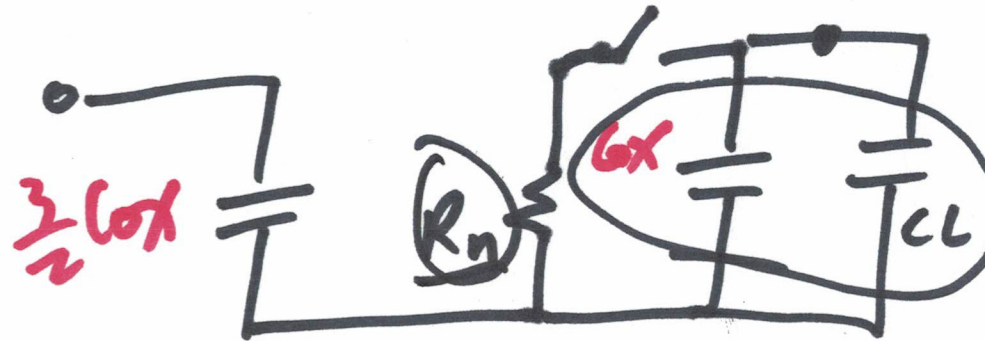
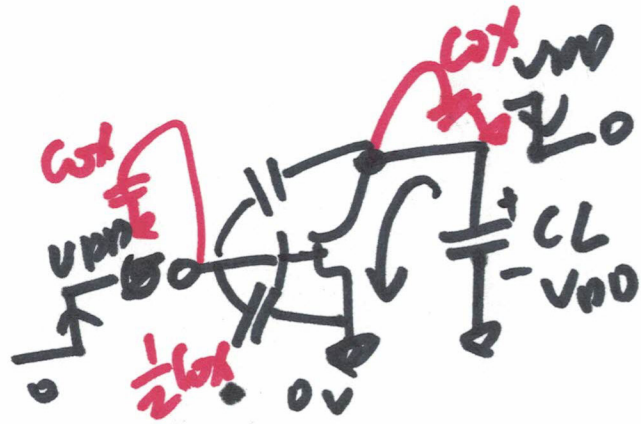
$$\Delta Q = \cancel{2V_{DD}C} 2V_{DD}C$$

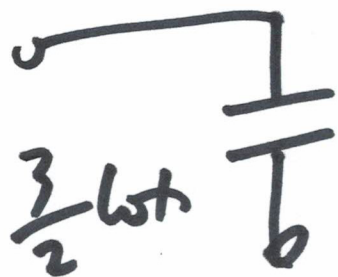
$$C_{eff} = \frac{\Delta Q}{V_{DD}} = \frac{2V_{DD}C}{V_{DD}} = 2C$$



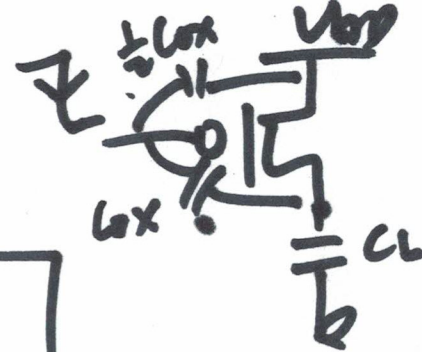
(1)







C_{ox}



$$C = \epsilon \frac{A}{t} \uparrow$$

Example P320

	sizes	$R_{n,p}$	$C_{oxn,p}$
NMOS	10μ/1μ	1.5K	17.5 fF
PMOS	30μ/1μ	1.5K	17.5 fF

t_{pHL}

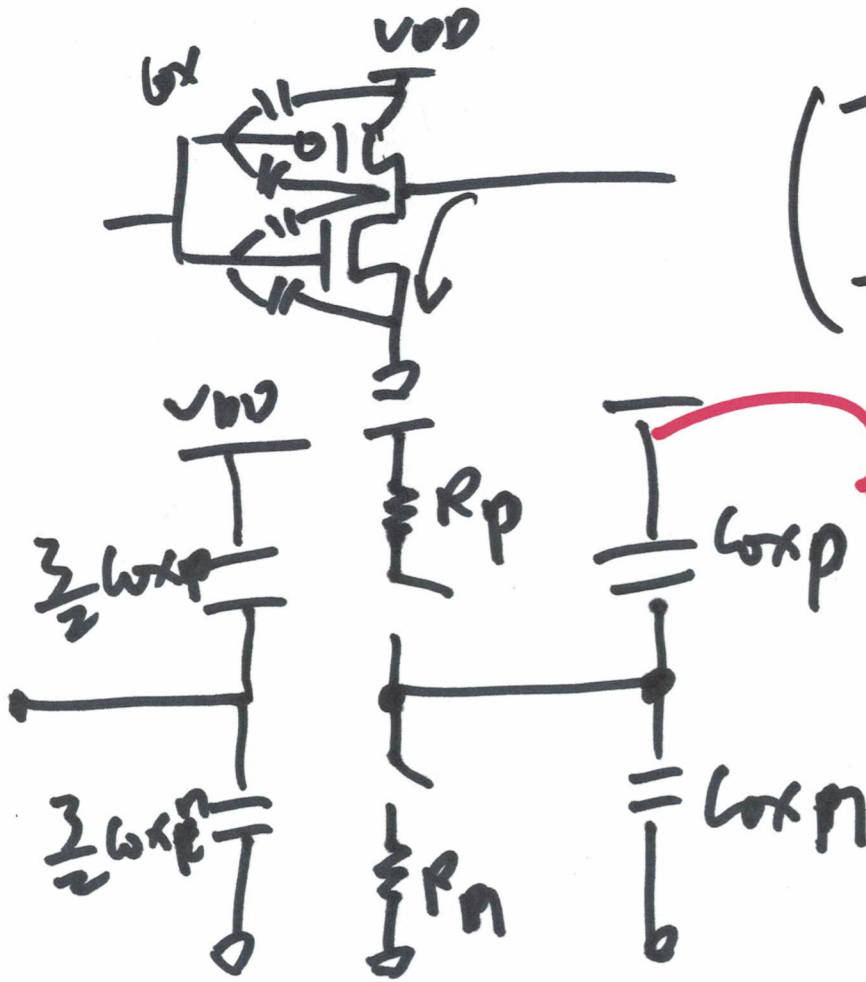
$$= 0.7 (R_n) (C_{ox} + C_L)$$

$$= 0.7 \cdot 3K (35fF + 50fF)$$



③

$$= \dots$$

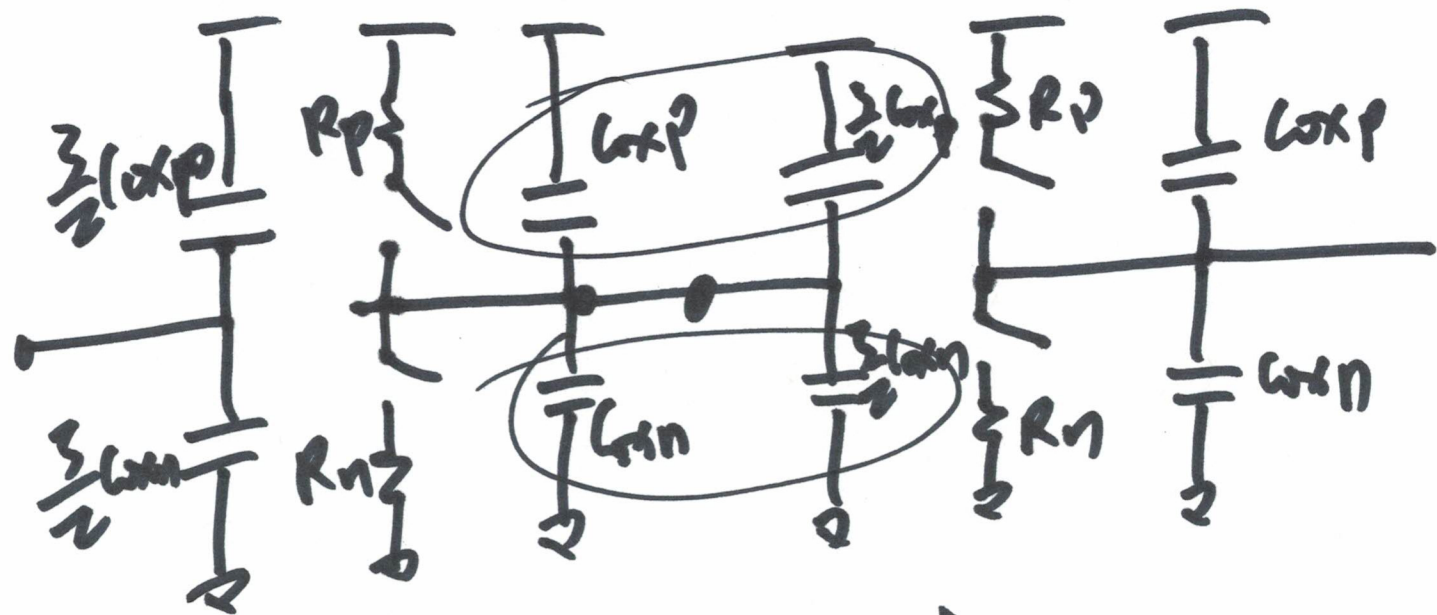


$$t_{pHL} = 0.7 R_n (C_{oxp} + C_{on})$$

$$t_{pLH} = 0.7 R_p (C_{oxp} + C_{on})$$

$$C_{in} = \frac{3}{2} C_{oxn} + \frac{3}{2} C_{oxp}$$

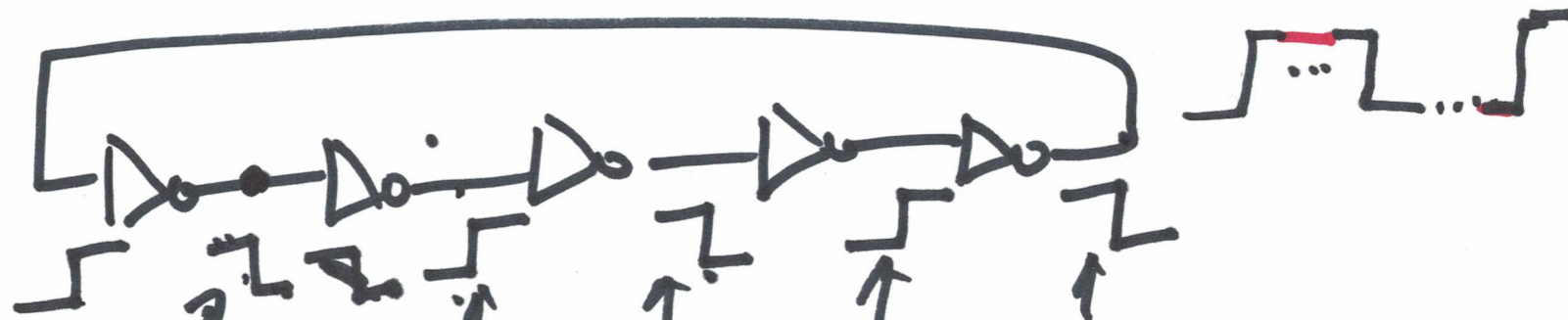
(4)



$$t_{pH} = 0.7 R_p \cdot \left(\frac{C_{oxp}}{2} + \frac{C_{dp}}{2} \right)$$

$$t_{pHL} = 0.7 R_n \cdot \left(\frac{C_{oxn}}{2} + \frac{C_{dn}}{2} \right)$$

(5)



$$\begin{aligned}
 & t_{pHL} + t_{pLH} + t_{pHL} + t_{pLH} + t_{pHL} \\
 & t_{pLH} + t_{pHL} + t_{pLH} + t_{pHL} + t_{pLH}
 \end{aligned}$$

$$\underline{f = \frac{1}{5(t_{pHL} + t_{pLH})} \cdot n}$$

$$f = \underline{500 \text{ MHz}}$$

$$\underline{\underline{11.2}}$$

(b)

Dynamic Power Dissipation



$$I_{avg} = \frac{Q_{tot}}{T} = \frac{V_{DD} \cdot C_{tot}}{T}$$

$$P_{avg} = I_{avg} \cdot V_{DD} = \frac{V_{DD}^2 \cdot C_{tot}}{T}$$
$$\Rightarrow V_{DD}^2 \cdot \underline{C_{tot}} \cdot \underline{f}$$